

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China







Silicon PIN Photodiode with Daylight Blocking Filter Version 1.4

BPW 34 FS



Features:

- Especially suitable for the wavelength range of 780 nm to 1100 nm
- Short switching time (typ. 20 ns)
- · DIL plastic package with high packing density
- · Suitable for reflow soldering
- The product qualification test plan is based on the guidelines of AEC-Q101-REV-C, Stress Test Qualification for Automotive Grade Discrete Semiconductors.

Applications

- Automotive (eg rain sensor, headset)
- · IR remote control of hi-fi and TV sets, dimmers, remote controls of various equipment
- Photointerrupters

Ordering Information

Туре:	Photocurrent	Ordering Code
	I _P [μΑ]	
	$\lambda = 950 \text{ nm}, E_e = 1 \text{ mW/cm}^2, V_R = 5 \text{ V}$	
BPW 34 FS	50 (≥ 40)	Q65110A2700



Maximum Ratings $(T_A = 25 \, ^{\circ}C)$

Parameter	Symbol	Values	Unit
Operating and storage temperature range	T _{op} ; T _{stg}	-40 100	°C
Reverse voltage	V _R	16	V
Reverse voltage (t < 2 min)	V _R	32	V
Total Power dissipation	P _{tot}	150	mW
ESD withstand voltage (acc. to ANSI/ ESDA/ JEDEC JS-001 - HBM)	V _{ESD}	2000	V

Characteristics ($T_A = 25$ °C)

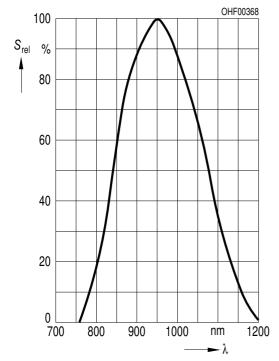
Characteristics (FA = 20 C)				
Parameter		Symbol	Values	Unit
Photocurrent $(V_R = 5 \text{ V}, \lambda = 950 \text{ nm}, E_e=1 \text{ mW/cm}^2)$	(typ (min))	I _P	50 (≥ 40)	μΑ
Wavelength of max. sensitivity	(typ)	$\lambda_{\text{S max}}$	950	nm
Spectral range of sensitivity	(typ)	λ _{10%}	(typ) 780 1100	nm
Radiant sensitive area	(typ)	Α	7.02	mm ²
Dimensions of radiant sensitive area	(typ)	LxW	2.65 x 2.65	mm x mm
Half angle	(typ)	φ	± 60	0
Dark current (V _R = 10 V)	(typ (max))	I _R	2 (≤ 30)	nA
Spectral sensitivity of the chip $(\lambda = 950 \text{ nm})$	(typ)	S _{\lambda typ}	0.7	A/W
Quantum yield of the chip $(\lambda = 950 \text{ nm})$	(typ)	η	0.91	Electro ns /Photon
Open-circuit voltage ($E_e = 0.5 \text{ mW/cm}^2$, $\lambda = 950 \text{ nm}$)	(typ (min))	Vo	330 (≥ 275)	mV
Short-circuit current (E _e = 0.5 mW/cm ² , λ = 950 nm)	(typ)	I _{SC}	25	μΑ
Rise and fall time $(V_R = 5 \text{ V}, R_L = 50 \Omega, \lambda = 850 \text{ nm}, I_P = 800 \mu\text{A})$	(typ)	t _r , t _f	0.02	μs
Forward voltage $(I_F = 100 \text{ mA}, E = 0)$	(typ)	V _F	1.3	V
Capacitance $(V_R = 0 \text{ V}, f = 1 \text{ MHz}, E = 0)$	(typ)	C ₀	72	pF
Temperature coefficient of V _O	(typ)	TC _V	-2.6	mV / K
$(I_{F} = 100 \text{ mA}, E = 0)$ Capacitance $(V_{R} = 0 \text{ V}, f = 1 \text{ MHz}, E = 0)$	(typ)	C ₀	72	pF



Parameter		Symbol	Values	Unit
Temperature coefficient of I_{SC} ($\lambda = 950 \text{ nm}$)	(typ)	TC _I	0.18	% / K
Noise equivalent power $(V_R = 10 \text{ V}, \lambda = 950 \text{ nm})$	(typ)	NEP	0.036	pW / Hz ^{1/2}
Detection limit $(V_R = 10 \text{ V}, \lambda = 950 \text{ nm})$	(typ)	D*	7.3e12	cm x Hz ^{1/2} / W

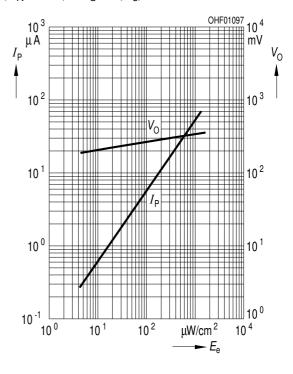
Relative Spectral Sensitivity $^{1)\,page\ 12}$

$$S_{rel} = f(\lambda)$$



Photocurrent / Open-Circuit Voltage 1) page 12

$$I_P (V_R = 5 V) / V_O = f(E_e)$$

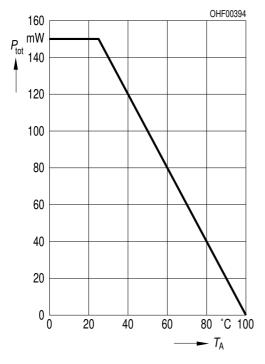


Version 1.4

BPW 34 FS

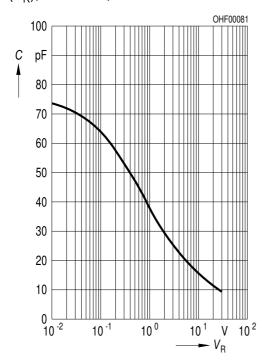
Power Consumption

$$P_{tot} = f(T_A)$$



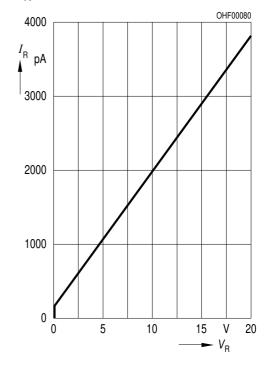
Capacitance 1) page 12

$$C = f(V_R)$$
, $f = 1 MHz$, $E = 0$



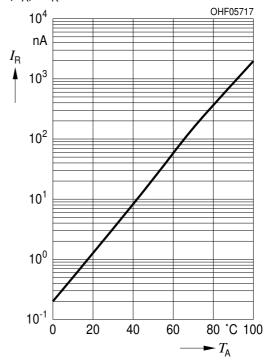
Dark Current 1) page 12

$$I_R = f(V_R), E = 0$$



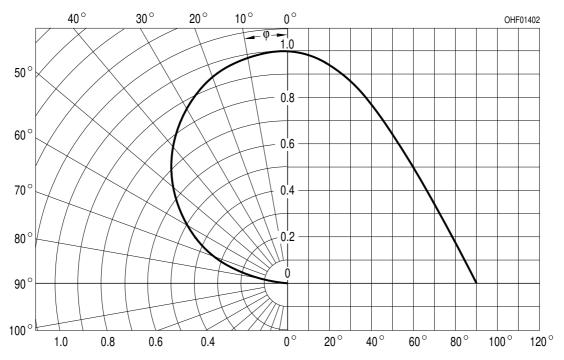
Dark Current 1) page 12

$$I_R = f(T_A), V_R = 10 \text{ V}, E = 0$$

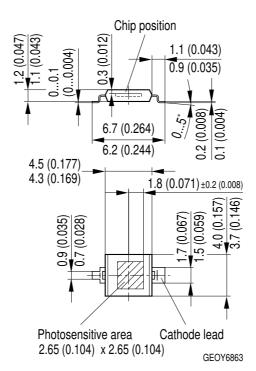


Directional Characteristics 1) page 12

$$S_{rel} = f(\phi)$$



Package Outline



Dimensions in mm (inch).

Package

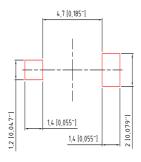
SMT DIL, Epoxy



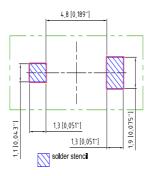
Approximate Weight:

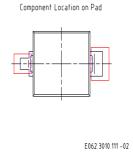
43 mg

Recommended Solder Pad





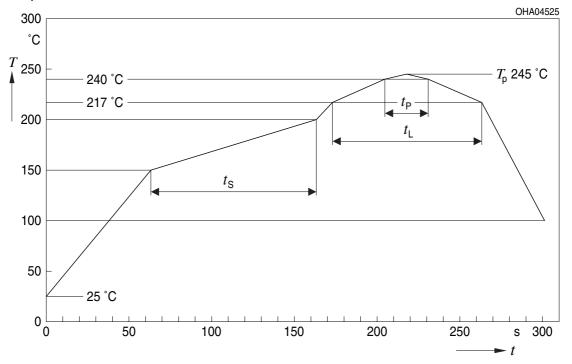




Dimensions in mm (inch).

Reflow Soldering Profile

Product complies to MSL Level 4 acc. to JEDEC J-STD-020D.01



OHA04612

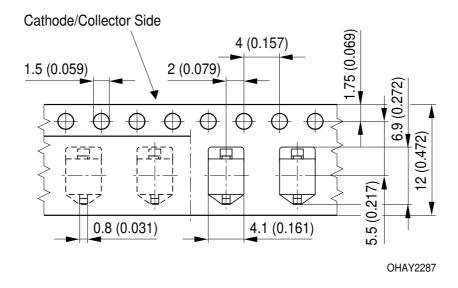
Profile Feature	Symbol	Pb-Free (SnAgCu) Assembly			Unit
Profil-Charakteristik	Symbol	Minimum	Recommendation	Maximum	Einheit
Ramp-up rate to preheat*) 25 °C to 150 °C			2	3	K/s
	t _s	60	100	120	S
Ramp-up rate to peak*) T _{Smax} to T _P			2	3	K/s
Liquidus temperature	T _L		217		°C
Time above liquidus temperature	t_		80	100	s
Peak temperature	T _P		245	260	°C
Time within 5 °C of the specified peak temperature T _P - 5 K	t _P	10	20	30	s
Ramp-down rate* T _P to 100 °C			3	6	K/s
Time 25 °C to T _P				480	S

All temperatures refer to the center of the package, measured on the top of the $\overline{\text{component}}$

* slope calculation DT/Dt: Dt max. 5 s; fulfillment for the whole T-range



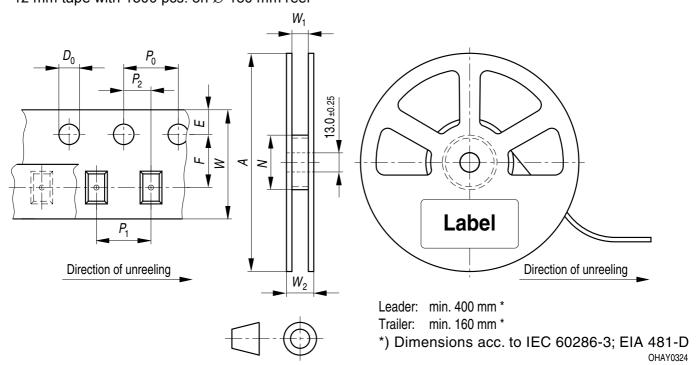
Taping



Dimensions in mm (inch).

Tape and Reel

12 mm tape with 1500 pcs. on \varnothing 180 mm reel



Tape dimensions [mm]

W	P ₀	P ₁	P ₂	D_0	E	F
12 + 0.3 / - 0.1	4 ± 0.1	4 ± 0.1 or 8 ± 0.1	2 ± 0.05	1.5 ± 0.1	1.75 ± 0.1	5.5 ± 0.05

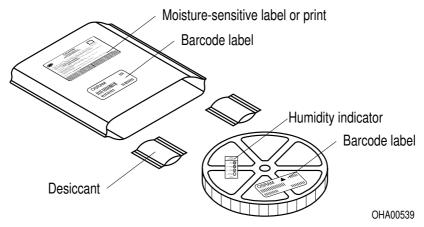
Reel dimensions [mm]

Α	W	N _{min}	W ₁	W _{2max}
180	12	60	12.4 + 2	18.4

Barcode-Product-Label (BPL)



Dry Packing Process and Materials

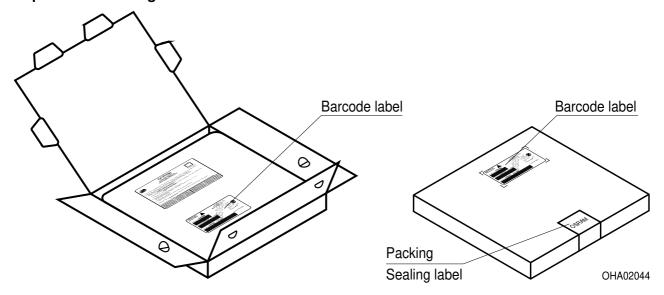


Note:

Moisture-sensitive product is packed in a dry bag containing desiccant and a humidity card. Regarding dry pack you will find further information in the internet. Here you will also find the normative references like JEDEC.



Transportation Packing and Materials



Dimensions of transportation box in mm

Width	Length	Height
195 ± 5	195 ± 5	30 ± 5



Disclaimer

Language english will prevail in case of any discrepancies or deviations between the two language wordings.

Attention please!

The information describes the type of component and shall not be considered as assured characteristics.

Terms of delivery and rights to change design reserved. Due to technical requirements components may contain dangerous substances.

For information on the types in question please contact our Sales Organization.

If printed or downloaded, please find the latest version in the Internet.

Packing

Please use the recycling operators known to you. We can also help you – get in touch with your nearest sales office. By agreement we will take packing material back, if it is sorted. You must bear the costs of transport. For packing material that is returned to us unsorted or which we are not obliged to accept, we shall have to invoice you for any costs incurred.

Components used in life-support devices or systems must be expressly authorized for such purpose! Critical components* may only be used in life-support devices** or systems with the express written approval of OSRAM OS.

- *) A critical component is a component used in a life-support device or system whose failure can reasonably be expected to cause the failure of that life-support device or system, or to affect its safety or the effectiveness of that device or system.
- **) Life support devices or systems are intended (a) to be implanted in the human body, or (b) to support and/or maintain and sustain human life. If they fail, it is reasonable to assume that the health and the life of the user may be endangered.



Glossary

Typical Values: Due to the special conditions of the manufacturing processes of LED, the typical data or calculated correlations of technical parameters can only reflect statistical figures. These do not necessarily correspond to the actual parameters of each single product, which could differ from the typical data and calculated correlations or the typical characteristic line. If requested, e.g. because of technical improvements, these typ. data will be changed without any further notice.



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